TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

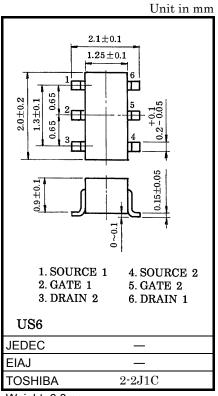
HN1K02FU

High Speed Switching Applications Analog Switch Applications

- 2.5 V gate drive.
- Low threshold voltage: $V_{th} = 0.5V \sim 1.5V$
- High speed
- Enhancement-mode
- Small package

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Drain-Source voltage	V _{DS}	20	V
Gate-Source voltage	V _{GSS}	10	V
DC Drain current	I _D	50	mA
Drain power dissipation	P _D *	200	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C



Weight: 6.8mg

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

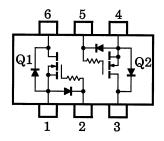
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

* Total rating

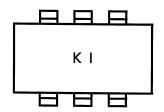
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Chara	cteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Gate leakage current		I _{GSS}	V _{GS} = 10V, V _{DS} = 0	_	_	1	μΑ
Drain-Source breakdown voltage		V _{(BR) DSS}	I _D = 100μA, V _{GS} = 0	20	_	_	٧
Drain cut-off cur	rent	I _{DSS}	V _{DS} = 20V, V _{GS} = 0	_	_	1	μA
Gate threshold v	oltage	V _{th}	V _{DS} = 3V, I _D = 0.1mA	0.5	_	1.5	V
Forward transfer	admittance	Y _{fs}	V _{DS} = 3V, I _D = 10mA	20	_	_	mS
Drain-Source ON resistance		R _{DS} (ON)	I _D = 10mA, V _{GS} = 2.5V	_	20	40	Ω
Input capacitance		C _{iss}	V _{DS} = 3V, V _{GS} = 0, f = 1MHz	_	5.5	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 3V, V _{GS} = 0, f = 1MHz	_	1.6	_	pF
Output capacitance		C _{oss}	V _{DS} = 3V, V _{GS} = 0, f = 1MHz	_	6.5	_	pF
Switching time	Turn-on time	t _{on}	V _{DD} = 3V, I _D = 10mA, V _{GS} = 0~2.5V	_	0.14	_	μs
	Turn-off time	t _{off}	V _{DD} = 3V, I _D = 10mA, V _{GS} = 0~2.5V	_	0.14	_	μs

Equivalent Circuit (Top View)

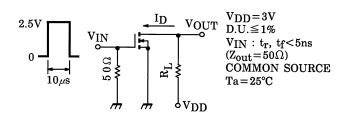


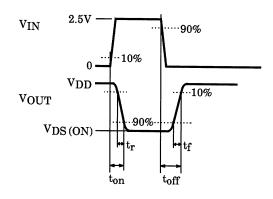
Marking

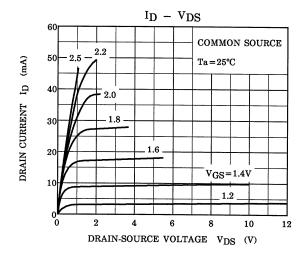


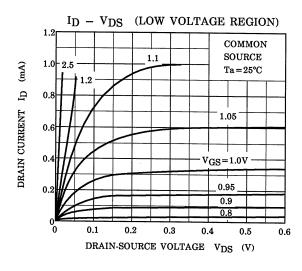
(Q1,Q2 Common)

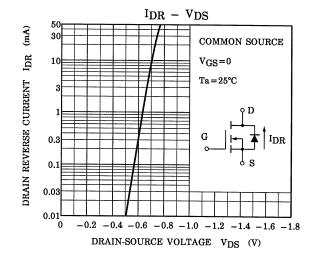
Switching Time Test Circuit

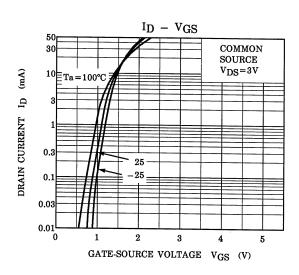




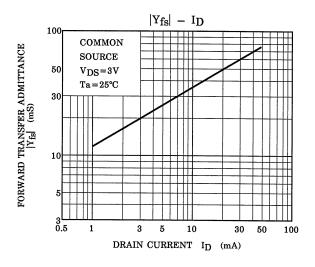


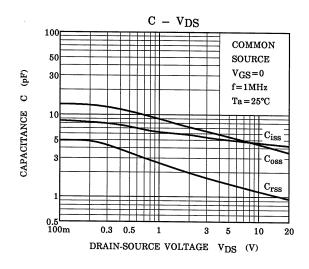


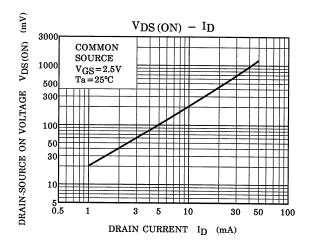


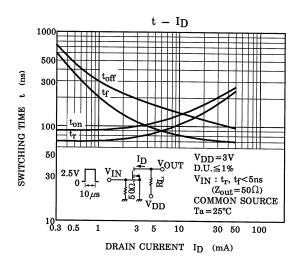


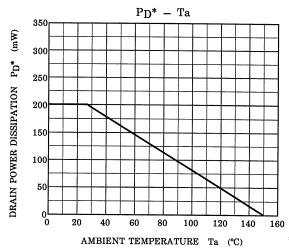
(Q1,Q2 Common)











* : Total Rating

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20070701-EN GENERAL

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